

# Morphological and structural changes in reducing and steam atmospheres of SiO<sub>2</sub>-supported Rh catalysts

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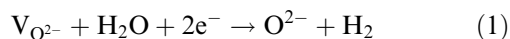
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Reduced centres are formed at the silica surface during the pretreatment of Rh/SiO<sub>2</sub> catalysts at high temperatures (500–900°C). These centres can be titrated with steam according to the reaction: reduced centre + H<sub>2</sub>O → oxidized centre + H<sub>2</sub>. The selective formation of H<sub>2</sub> when catalysts pretreated in D<sub>2</sub> are reacted with H<sub>2</sub>O confirms that steam is decomposed during the titration reaction. XRD, TEM and EDX were used to investigate the morphological and structural changes in the catalysts. Owing to the formation of Rh<sub>2</sub>Si alloy, the number of reduced centres formed on SiO<sub>2</sub> is much greater than the number found with Rh/Al<sub>2</sub>O<sub>3</sub> reduced under similar conditions.

**Keywords:** metal support interactions, support reduction, Rh/SiO<sub>2</sub> catalysts

## 1. Introduction

High-temperature reduction of supported metal catalysts can cause profound changes in the metal surface areas, in the surface composition and in the particle morphology. High-temperature treatments can also create structural and chemical modifications of the support, particularly in the vicinity of metal particles. Supports inducing strong metal–support interactions (SMSI) can be reduced or oxidized under mild conditions, particularly in the presence of metals [1]. Duprez et al. [2] proposed a technique for measuring the number of reduced centres of TiO<sub>2</sub> in Rh, Pt and Ni/TiO<sub>2</sub> catalysts. This technique is based on the measurement of the amount of H<sub>2</sub> produced by oxidation with H<sub>2</sub>O pulses in accordance with the following equation:



where V<sub>O<sup>2-</sup></sub> is an anion vacancy and 2e<sup>-</sup> represents electrons delocalized in the conduction band of TiO<sub>2</sub> (reduced state). The use of steam, instead of O<sub>2</sub>, for the oxidation of these reduced centres presents two main advantages:

(a) the reaction is selective: only the reduced centres of the support are oxidized, while the metals remain essentially in their reduced state;

(b) hydrogen can be detected with a very high sensitivity.

This technique was applied successfully to Rh and Pt/Al<sub>2</sub>O<sub>3</sub> catalysts [3]. We showed that defect centres, rather than reduced centres, were formed on alumina, in the close proximity of the metal particles. We report here the results of an investigation carried out on silica-supported rhodium catalysts.

## 2. Experimental

### 2.1. Catalyst preparation

Rhône-Poulenc DBM200 silica (250 m<sup>2</sup> g<sup>-1</sup>) was used as a carrier. The catalysts were prepared by wet impregnation of the support with aqueous solutions of RhCl<sub>3</sub>·3H<sub>2</sub>O. After impregnation the catalysts were dried overnight at 120°C and then calcined in air at 450°C for 4 h. The samples were characterized by H<sub>2</sub> chemisorption (H<sub>C</sub>), oxygen titration (O<sub>T</sub>) and hydrogen titration (H<sub>T</sub>) carried out in a chromatographic reactor described previously [4].

### 2.2. H<sub>2</sub> reduction and H<sub>2</sub>O titration

The sample (0.2 g) was heated at 10°C min<sup>-1</sup> under a flow of ultrapure H<sub>2</sub> (20 cm<sup>3</sup> min<sup>-1</sup>; less than 1 ppm of impurities) up to the reduction temperature *T<sub>R</sub>*. It was maintained at this temperature for 1 h and then purged under a flow of ultrapure Ar (20 cm<sup>3</sup> min<sup>-1</sup>; < 1 ppm impurities) for 30 min and cooled down to the temperature of oxidation by steam *T<sub>ox</sub>*. Pulses of steam (56 μmol H<sub>2</sub>O) were then injected on the catalyst sample every ten

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minutes. H<sub>2</sub> was analyzed by gas chromatography on a 5A molecular sieve column coupled with a thermal conductivity detector. We observed that the amount of H<sub>2</sub> decreased rapidly as a function of the number of pulse and then stabilized at a very low value after the fourth pulse of water. The same procedure was used for the experiments in which both the temperature of reaction with steam was varied and the temperature of reduction was fixed.

### 2.3. H/D isotopic labelling

H<sub>2</sub> formation upon H<sub>2</sub>O injection could result from some hydrogen stored in the catalyst during its reduction. To check this, a H/D isotopic labelling study was carried out. The sample was reduced in D<sub>2</sub> for 30 min and purged in Ar for 30 min. Pulses of water (H<sub>2</sub>O) were then injected. The effluents were analyzed by mass spectrometry (Balzers QMG 420) coupled with the gas chromatographic apparatus via a capillary connection system. The mass spectrometer response was corrected from the differences in the ionization probability and in the capillary diffusivity of H<sub>2</sub>, HD and D<sub>2</sub>.

### 2.4. X-ray diffraction

XRD analyses were carried out in a Siemens D500 powder diffractometer using Cu K $\alpha_1$  radiation (0.15406 nm). About 50 mg of catalyst were pressed in the sample holder. The crystalline phases were identified by comparison with JCPDS files: Rh metal (05-685), SiO<sub>2</sub> cristobalite (39-1425) and Rh<sub>2</sub>Si alloy (37-1416).

### 2.5. Transmission electron microscopy and energy-dispersive X-ray analysis

TEM was performed in a Philips CM120 microscope with a resolution of 0.35 nm. The sample was crushed, ultrasonically suspended in ethanol, deposited on a Cu grid previously covered with a thin layer of carbon. EDX element analyses were carried out in the STEM mode of the microscope using a Si(Li) Super UTW detector with a resolution of 148.5 eV. In order to minimize the contribution of the support, only the particles located on the edges of the silica patches were analysed by EDX.

## 3. Results

### 3.1. Characterization of the fresh catalysts

The results of the chemisorptions (H<sub>C</sub>) and of the titrations (O<sub>T</sub>, H<sub>T</sub>) carried out on the fresh catalysts reduced at 400°C are reported in table 1. This table also gives the values of the metal dispersions calculated by %D = 100 H<sub>C</sub>/M<sub>t</sub>, where H<sub>C</sub> is the number of chemi-

Table 1  
Dispersion measurements of the fresh catalysts reduced at 400°C for 16 h. Hydrogen and oxygen uptakes are given in  $\mu\text{mol at. g}^{-1}$

Catalyst	wt% metal	$\mu\text{mol Rh g}^{-1}$	H <sub>C</sub>	O <sub>T</sub>	H <sub>T</sub>	%D
4Rh/SiO <sub>2</sub>	4.12	400.3	51	86	177	13
0.4Rh/SiO <sub>2</sub>	0.38	36.9	4.6	6.6	19.0	12

sorbed hydrogen atoms and M<sub>t</sub> the number of metal atoms in the sample.

### 3.2. H<sub>2</sub>O titration: effect of T<sub>R</sub> on H<sub>2</sub> production (T<sub>ox</sub> = 500°C)

The effect of the reduction temperature T<sub>R</sub> on the number of reduced centres, as determined by the H<sub>2</sub>O titration technique, was investigated. Figure 1 shows the cumulative amounts Q<sub>H</sub> of H<sub>2</sub> produced during the titration at T<sub>ox</sub> = 500°C (five pulses of H<sub>2</sub>O). Q<sub>H</sub>, very low on the samples reduced at 500°C, increases rapidly with T<sub>R</sub>. Figure 1 also shows that Q<sub>H</sub> depends strongly on the metal loading. In separate experiments, it was proved that the bare support treated in H<sub>2</sub> at high temperature (800–900°C) could not decompose the water molecule. This shows that the metal-free silica surface is little or not upset under these conditions.

The 4Rh/SiO<sub>2</sub> catalyst sample has been characterized by H<sub>2</sub> chemisorption before (just reduced at T<sub>R</sub> for 1 h) and after H<sub>2</sub>O titration. The results (table 2) clearly indicate that the high-temperature (HT) reduction suppresses the ability of the catalyst to chemisorb hydrogen while H<sub>2</sub>O titration restores the initial properties of the catalyst, either totally (T<sub>R</sub> < 800°C) or partially (T<sub>R</sub> > 800°C). This is indicative of a strong metal-support interaction (SMSI) effect as reported earlier by Tauster et al. in the case of TiO<sub>2</sub>-supported catalysts [1]. This annihilation by H<sub>2</sub>O of the SMSI effect is comparable to what was observed with oxygen [5–7].

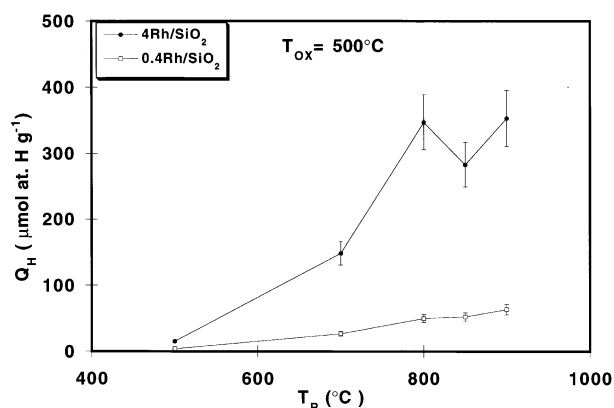


Figure 1. Overall amount of H<sub>2</sub> formed in H<sub>2</sub>O titration (five pulses) over Rh/SiO<sub>2</sub> as a function of the reduction temperature T<sub>R</sub>.

Table 2  
H<sub>2</sub> chemisorption on the 4Rh/SiO<sub>2</sub> catalyst (a) before H<sub>2</sub>O titration (1 h at  $T_R$ ), (b) after H<sub>2</sub>O titration at 500°C (without any further reduction)

$T_R$ (°C)	$T_{ox}$ (°C)	H <sub>C</sub> (a) (μmol at. g <sup>-1</sup> )	H <sub>C</sub> (b) (μmol at. g <sup>-1</sup> )
700	500	9.2	51.3
800	500	0	47.5
850	500	0	24.0
900	500	0	5.1

High-temperature reduction (1 h in H<sub>2</sub>) induces a significant sintering of the metal particles above 800°C (table 2), which can explain the minimum of  $Q_H$  observed at 850°C (figure 1). The amount of reduced sites created on the support depends both on the rate of hydrogen flux  $F_H$  across the metal/support interface and on the intrinsic rate  $R_{red}$  of formation of these reduced sites. Only  $F_H$  (proportional to the specific perimeter of the metal particles) depends on the metal sintering. When  $T_R$  is increased,  $F_H$  decreases significantly above 800°C while  $R_{red}$  increases continuously, depending only on the activation energy of the surface reduction reaction. Owing to the balance between these two processes,  $Q_H$  first decreases between 800 and 850°C (determining effect of  $F_H$ ) before increasing again above 850°C (determining effect of  $R_{red}$ ).

### 3.3. H<sub>2</sub>O titration: effect of $T_{ox}$ on H<sub>2</sub> production ( $T_R = 850^\circ\text{C}$ )

The variations of  $Q_H$  with the temperature of H<sub>2</sub>O titration are shown in figure 2. For a given catalyst and for the same temperature of reduction (850°C), the amount of hydrogen produced in titration slightly increases with  $T_{ox}$ . Apparently, part of the sites created by reduction at 850°C are not easily titrated by H<sub>2</sub>O. The  $Q_H(500)/Q_H(900)$  ratio amounts to 65% for 0.4Rh/SiO<sub>2</sub> and 75% for 4Rh/SiO<sub>2</sub>. Moreover, it seems that not all

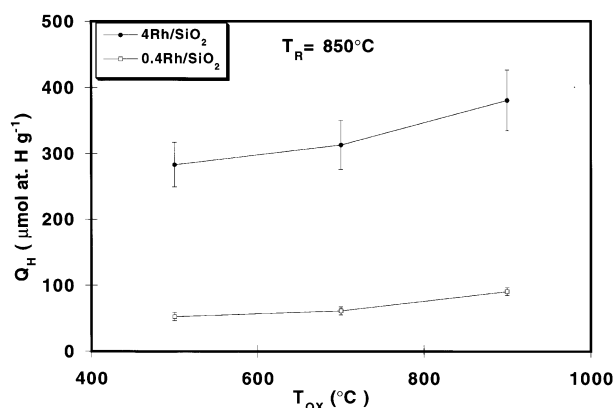


Figure 2. Overall amount of H<sub>2</sub> formed in H<sub>2</sub>O titration (five pulses) over Rh/SiO<sub>2</sub> as a function of the titration temperature  $T_{ox}$ .

the reduced sites can be titrated at 900°C, which proves that certain sites are deeply embedded in the silica matrix.

Hydrogen chemisorptions were carried out after titration (table 3). Keeping in mind that there was no hydrogen uptake on the catalyst merely reduced at 850°C (not yet titrated), the data of table 3 confirm that H<sub>2</sub>O titration allows the catalyst to recover a significant part of its chemisorption properties. However, titration above 700°C is accompanied with a definite sintering of the catalyst which adds to the sintering due to the high-temperature reduction.

### 3.4. H/D isotopic labelling

H<sub>2</sub>O decomposition on reduced silica centres is the most likely hypothesis for explaining the H<sub>2</sub> formation in H<sub>2</sub>O titration. Another plausible hypothesis is the desorption, by water, of the hydrogen which could have been stored in the catalyst during HT reduction. Figure 3 shows the isotopic analysis of the hydrogen produced by reaction of H<sub>2</sub>O on a catalyst sample reduced in D<sub>2</sub>. The production of H<sub>2</sub> is definitely greater than that of HD of D<sub>2</sub>, which confirms the first hypothesis (H<sub>2</sub>O decomposition). Moreover, HD and D<sub>2</sub> can be formed possibly via a secondary reaction of exchange between H<sub>2</sub> and the OD groups of silica. Nevertheless, the fact that D<sub>2</sub> is the first isotopomer to be formed in the reaction (see the first pulse in figure 3) implies that the second hypothesis (D<sub>2</sub> desorption) cannot be definitely discarded.

### 3.5. X-ray diffraction

The 4% Rh/SiO<sub>2</sub> catalyst was examined by XRD after different treatments: reduction at 500°C (4Rh/SiO<sub>2</sub>R500), reduction at 980°C (4Rh/SiO<sub>2</sub>R980) and steam-treatment at 980°C after reduction at that temperature (4Rh/SiO<sub>2</sub>R980H<sub>2</sub>O980). Rh metal is the only rhodium species detected in the sample reduced at 500°C (figure 4a). In 4Rh/SiO<sub>2</sub>R980, the peaks corresponding to the cfc structure of Rh disappear while a new phase identified as Rh<sub>2</sub>Si can be observed (figure 4b). This rhodium silicide has an orthorhombic structure ( $a = 0.5410$  nm;  $b = 0.3928$  nm and  $c = 0.7388$  nm). It reacts with steam at 980°C and reforms metallic rhodium and a well-crystallized SiO<sub>2</sub> having the cristobalite

Table 3  
H<sub>2</sub> chemisorption on the 4Rh/SiO<sub>2</sub> catalyst after H<sub>2</sub>O titration at different temperatures. There is no hydrogen uptake on the catalyst reduced at 850°C before H<sub>2</sub>O injection

$T_R$ (°C)	$T_{ox}$ (°C)	H <sub>C</sub> (μmol at. g <sup>-1</sup> )
850	700	24.0
850	800	23.1
850	900	12.2

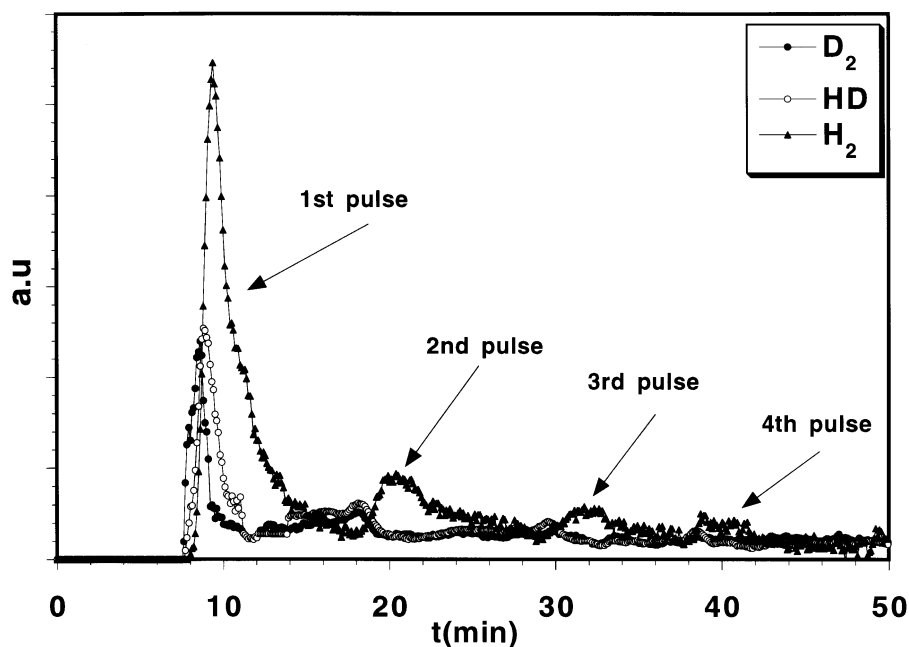


Figure 3.  $\text{H}_2$ , HD and  $\text{D}_2$  formation upon  $\text{H}_2\text{O}$  pulses over  $4\text{Rh}/\text{SiO}_2$  reduced in  $\text{D}_2$ .

structure (figure 4c). It is worth noting that the steam treatment at  $980^\circ\text{C}$  has not entirely destroyed the rhodium silicide. The mean particle size of rhodium in  $4\text{Rh}/\text{SiO}_2\text{R500}$  is 6.7 nm, which corresponds to a 14% dispersion, a value very close to that found by  $\text{H}_2$  chemisorption for the fresh catalyst (table 1). XRD also shows that HT treatments lead to a sintering of rhodium: the mean size of  $\text{Rh}_2\text{Si}$  particles is 11.5 nm in  $4\text{Rh}/\text{SiO}_2\text{R980}$  while that of Rh in  $4\text{Rh}/\text{SiO}_2\text{R980H}_2\text{O980}$  would be 17.2 nm. Similar diffractograms were obtained with the catalyst reduced or oxidized at a lower temperature. However,

owing to a smaller particle size in these samples, the different XRD peaks were not so well-resolved as in the diffractograms of figure 4.

### 3.6. Electron microscopy and energy-dispersive element analysis

Figure 5 shows representative micrographs of the  $4\text{Rh}/\text{SiO}_2$  catalyst after different treatments. In  $4\text{Rh}/\text{SiO}_2\text{R500}$  (figure 5a), most Rh particles have a three-dimensional, spherical shape, in agreement with pre-

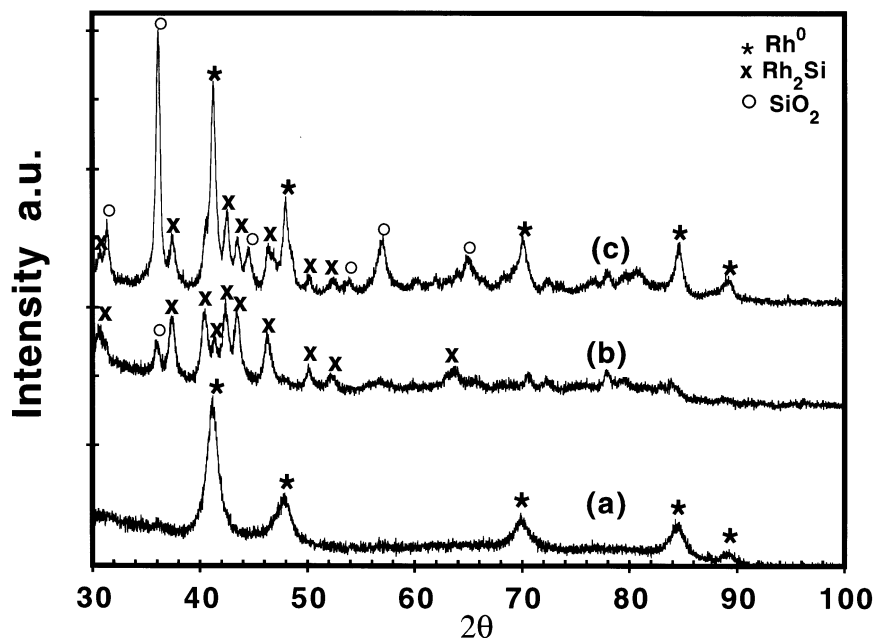


Figure 4. X-ray diffractograms of  $4\text{Rh}/\text{SiO}_2$  catalyst: (a)  $4\text{Rh}/\text{SiO}_2\text{R500}$ , (b)  $4\text{Rh}/\text{SiO}_2\text{R980}$ , (c)  $4\text{Rh}/\text{SiO}_2\text{R980H}_2\text{O980}$ .

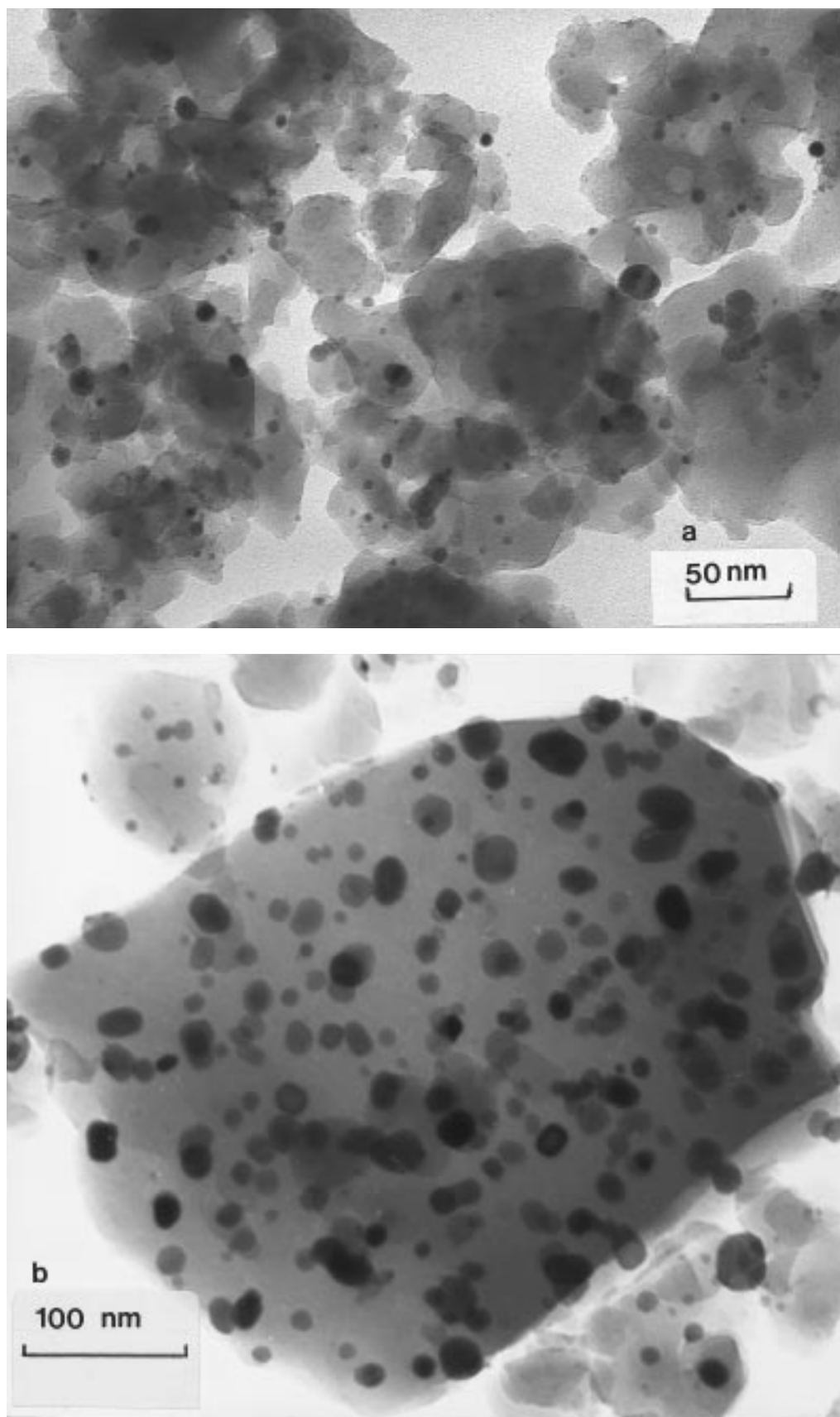


Figure 5. TEM micrographs of 4Rh/ $\text{SiO}_2$  catalyst: (a) 4Rh/ $\text{SiO}_2$ R500, (b) 4Rh/ $\text{SiO}_2$ R980, (c) 4Rh/ $\text{SiO}_2$ R980H<sub>2</sub>O980. (Continued on next page.)

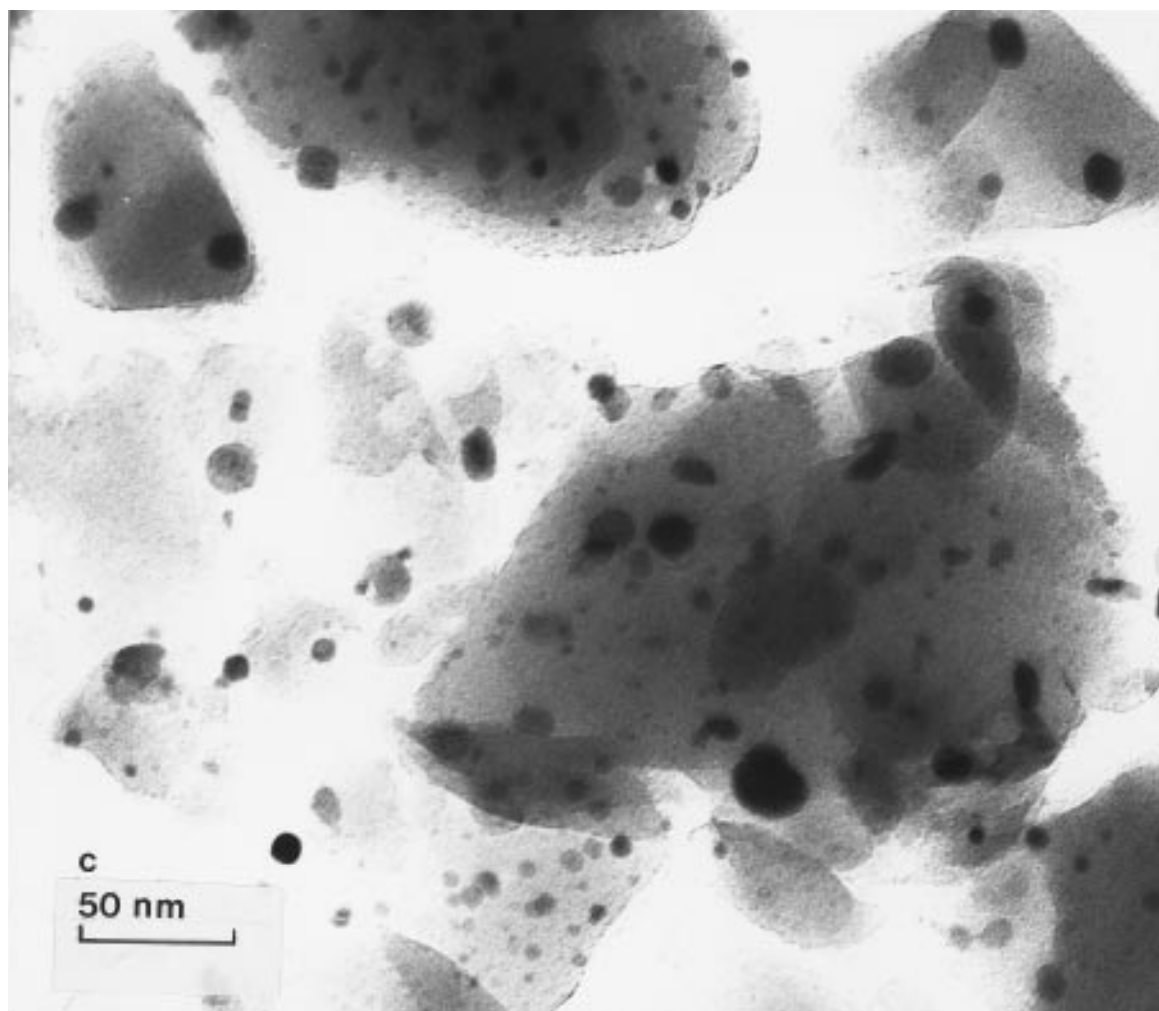


Figure 5. (Continued.)

vious observations of Chakraborti et al. [8]. In 4Rh/SiO<sub>2</sub>R980 (figure 5b), a definite morphological change can be observed: numerous particles have a hexagonal shape, which can be related to the structural change ( $\text{Rh}^0 \rightarrow \text{Rh}_2\text{Si}$ ) induced by the high-temperature reduction. Moreover, an apparent spreading of the silicide particles on the support leads to low-contrast bidimensional crystallites. After the steam treatment at 980°C, most particles recover their initial spherical shape (figure 5c). However, certain particles seem to retain a hexagonal shape. This can be attributed to the presence of residual  $\text{Rh}_2\text{Si}$  particles or to a preferential (111) orientation of the rhodium particles [9].

EDX analysis was carried out to obtain information on the composition of the particles after the different treatments. In each case, ten particles were analysed, the mean composition being given in table 4. It has not been possible to eliminate the contribution of the support in the X-rays emitted from the selected area. However, the particles formed after high-temperature reduction have a high silicon content, which shows the formation of a new compound between rhodium and silicon. The EDX analysis confirms that this compound is destroyed by steam at 980°C and that the initial composition is restored.

#### 4. Discussion

This study has shown that a reduction of Rh/SiO<sub>2</sub> catalysts in H<sub>2</sub> above 500°C led to the appearance of reduced centres on the silica support. These reduced centres were analyzed by H<sub>2</sub>O titration according to the reaction:

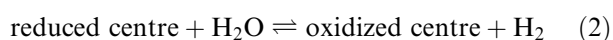


Table 4  
Normalized EDX atomic percentages of Rh and Si in the particles of 4Rh/SiO<sub>2</sub> after different treatments

Catalyst	%Rh (K <sub>α</sub> )	%Si (K <sub>α</sub> )	Rh/Si ratio
4Rh/SiO <sub>2</sub> R500	47	53	0.886
4Rh/SiO <sub>2</sub> R980	19.5	80.5	0.242
4Rh/SiO <sub>2</sub> R980H <sub>2</sub> O980	44.6	55.4	0.805

The experiments performed with the catalyst reduced in a flow of D<sub>2</sub> showed that the formation of H<sub>2</sub> was essentially due to the decomposition of water. A significant production of H<sub>2</sub> was observed with the Rh/silica catalysts and it was shown that  $Q_H$  increased significantly with the temperature of reduction  $T_R$  and slightly with the temperature of titration  $T_{ox}$ .

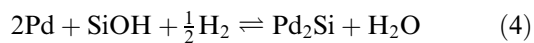
These results contrast with those obtained with Al<sub>2</sub>O<sub>3</sub>-supported catalysts [3], for which the amounts of H<sub>2</sub> produced in H<sub>2</sub>O titrations depended little on  $T_R$  and  $T_{ox}$  (figure 4). This was attributed to a limited number of reducible centres of Al<sub>2</sub>O<sub>3</sub>, exclusively located at the periphery of the metal particles. We showed that the number of Al ions in contact with the metal particles was approximately the third of the amount of H atoms produced in H<sub>2</sub>O titration.

The significant increase of  $Q_H$  with  $T_R$  shows that the reduction of silica is not limited to the silicon ions in close contact with the rhodium particles. As the presence of the metal is required for reducing the support, it can be concluded that a relatively large area of silica surrounding the rhodium particles is reduced after the HT treatment in H<sub>2</sub>. The silicon thus formed can react with the rhodium to form intermetallic compounds. The presence of an Rh<sub>2</sub>Si alloy in the 4Rh/SiO<sub>2</sub> catalyst reduced at high temperature was proved by XRD while TEM showed relatively flat alloy particles spread on the support. The formation of this rhodium silicide compound implies the reduction of SiO<sub>2</sub> in the presence of Rh and H<sub>2</sub>:



The formation of metal silicide compounds has been observed by different authors. Praliaud and Martin [10] reported that the activity of Ni/SiO<sub>2</sub> in benzene hydrogenation dramatically decreased after reduction of the catalyst sample at 850–900°C. Magnetic measurements revealed that the sample reduced at high temperature behaved as a Ni–Si alloy with a 11.5 at% Si composition. Juszczak and Karpinski [11,12] detected, by XRD, the formation of palladium silicides (Pd<sub>3</sub>Si and possibly Pd<sub>5</sub>Si) in Pd powder mixed with silica after high-temperature reduction at 600°C. However, similar experiments carried out with Pd/SiO<sub>2</sub> catalysts suggested the presence of Pd<sub>2</sub>Si after HT reduction [11]. Romanovsky and Lamber [13,14] used electron diffraction to show that Pt–Si alloys (mainly Pt<sub>2</sub>Si) were formed when thin films of Pt deposited on quartz glass substrates were reduced at temperatures as low as 550°C. During the formation of these Pt–Si alloys, Romanovsky and Lamber noticed a “wetting” of the quartz surface by platinum, a phenomenon similar to what we observed with the 4Rh/SiO<sub>2</sub>R980 catalyst. Microdiffraction analysis also showed the formation of palladium silicide (Pd<sub>2</sub>Si) on Pd/SiO<sub>2</sub> films treated in H<sub>2</sub> (10<sup>−2</sup> Pa) at 572°C [15]. These authors noticed that alloy formation was enhanced on hydroxylated silica surface, the reduction

of silanol groups (eq. (4)) being less demanding energetically than the reduction of silica (eq. (5)):



Wong and McCabe [16] did not observe any formation of new Rh–Si compounds after the reduction of their 1% Rh/SiO<sub>2</sub> catalyst in a flow of H<sub>2</sub> at 800°C. This is probably due to the oxidative post-treatment at 450°C applied to the catalyst before characterization. H<sub>2</sub>O titration leads partly to the re-oxidation of reduced silica and to the reformation of rhodium particles. XRD, TEM and EDX showed that the Rh<sub>2</sub>Si alloy crystallites were destroyed. Moreover, the chemisorptive properties of the metal were restored and no peak of Rh<sub>2</sub>O<sub>3</sub> was observed in the XRD spectra of the water-treated catalysts. This confirms that the noble metal is not oxidized by H<sub>2</sub>O during the titration reaction. The effect of water on catalysts exhibiting SMSI phenomena was investigated by Baker et al. in the case of Pt/TiO<sub>2</sub> specimens (films and powder) [7,17]. Water at 250°C annihilates SMSI effects and partly restores H<sub>2</sub> and CO chemisorption. Titania-supported catalysts have been the subject of in-depth studies, as a model of solids giving rise to SMSI effects. These effects are evident in catalysts reduced at relatively moderate temperatures (400–500°C). Titanium suboxides, such as Ti<sub>4</sub>O<sub>7</sub>, are then formed [17,18] and the noble metal can be deeply embedded in the reduced titania matrix [19–22]. However, an electron transfer from the titania suboxide to the noble metal accompanies the HT reduction [21,23] and, under certain conditions, direct Rh–Ti bonding was shown by XANES in Rh/TiO<sub>2</sub> catalysts reduced at 500°C, which suggested the formation of new structures resembling RhTi or Rh<sub>3</sub>Ti [24]. In the case of silica-supported catalysts, the formation of silica suboxides seems very unlikely and H<sub>2</sub> reduction leads to intermetallic compounds above 500°C. Once formed, the rhodium silicide appears to be relatively stable: H<sub>2</sub>O titration has

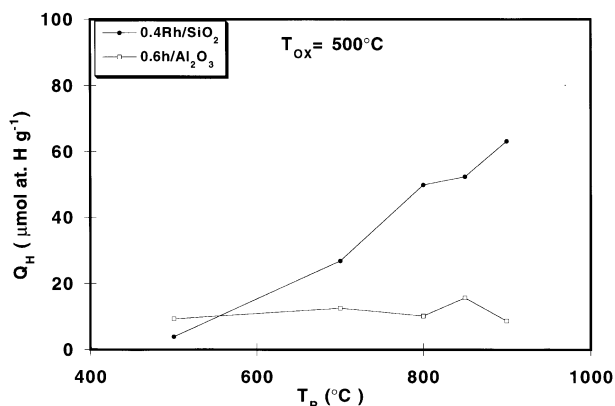


Figure 6. Amount of H<sub>2</sub> formed in H<sub>2</sub>O titration at 500°C. Comparison between Al<sub>2</sub>O<sub>3</sub>- and SiO<sub>2</sub>-supported Rh catalysts.

to be carried out at high temperatures to obtain a significant re-oxidation of the silicon in these rhodium silicides. Other studies are in progress to examine the effects of HT reduction and of H<sub>2</sub>O titration on the catalytic activity of these Rh/SiO<sub>2</sub> catalysts.

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